Appl. No. 10/007,397 Amdt. dated November 5, 2003 Reply to Office action of 8/5/2003

Am ndments to the Translated Sp cification:

Page 5, between lines 25 and 27, please add the following paragraph:

-- In accordance with an added feature of the invention, the first layer has a number of dopant atoms of the first conduction type and a number of dopant atoms of the second conduction type that are approximately identical. --

Page 16, between lines 7 and 9, please add the following paragraph:

-- The drain zone 60 has a first section 100 extending vertically to the second layer 26 and a second section 102 extending laterally at the level of the second layer 26. --